

## T495B475K016ATE1K5

**General Information** 

Series

Dielectric

T495, Tantalum, MnO2 Tantalum, Commercial Grade, 4.7 uF, 10%, 16 VDC, SMD, MnO2, Molded, Low ESR, 1.5 Ohms, 3528, 2.1 mm, 0.8 mm

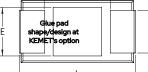
CATHODE (-) END VIEW



ANODE (+) END VIEW

Di W H T S F A B E G R X

SIDE VIEW



I KEME	Tis option	ai
	Shelf	Li
	L MSL	
Click here for the 3D m	odel.	
imensions	Speci	fi
3.5mm ·	+/-0.2mm Capac	cit
2.8mm ·	+/-0.2mm Tolera	in
1.9mm +	+/-0.2mm Voltag	ge
0.13mm	REF Temp	er
0.8mm	+0.1/-0.3mm Rated	T
2.2mm -	+/-0.1mm Dissip	at
1.9mm N	MIN Failure	e I
0.4mm	+/-0.15mm ESR	
2.2mm I	REF Ripple	e (
1.8mm F	REF	
0.5mm	REF Leaka	ıg
1mm RE	F	
0.1mm +	+/-0.1mm REF	

Style	SMD Chip
Description	SMD, MnO2, Molded, Low ESR
Features	Low ESR
RoHS	Yes
Termination	Tin
AEC-Q200	No
Typical Component Weight	107.45 mg
Shelf Life	156 Weeks
MSL	1

T495

MnO2 Tantalum

Specifications	
Capacitance	4.7 uF
Tolerance	10%
Voltage DC	16 VDC (85C), 10.72 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6% 120Hz 25C
Failure Rate	N/A
ESR	1500 mOhms (100kHz 25C)
Ripple Current	238 mA (rms, 100kHz 25C), 214.2 mA (rms, 85C), 95.2 mA (rms, 125C)
Leakage Current	0.8 uA (5min 25°C)

Packaging Specifications	
Packaging	T&R, 178mm
Packaging Quantity	2000

Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute – and we specifically disclaim – any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.

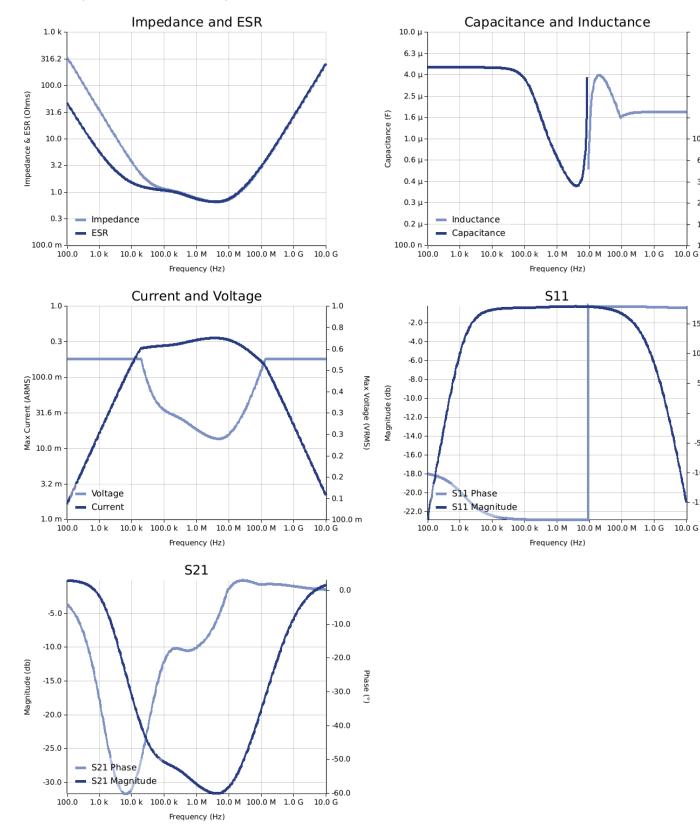


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### Simulations

For the complete simulation environment please visit K-SIM.



1.0 n

0.6 n

0.4 n

0.3 n

100.0 p 🗿

0.2 n a

63.1 p 🗄

39.8 p

25.1 p

15.8 p

10.0 p

150.0

100.0

50.0

0.0

-50.0

-100.0

-150.0

Phase (°)



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#### These are simulations.

This is not a specification!

The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

The responses shown do not represent a specified or implied maximum capability of the device for all applications.

- The ESR used for ripple "Ripple Current/Voltage vs. Frequency" plots is the ESR at ambient temperature.

- The ESR in the "Temperature Rise vs. Ripple Current" plots is adjusted to each incremental temperature rise before the power and ripple current is calculated. The effects shown herein are based on measured data from a multiple part sample of the parts in question. Ripple capability of this device will be factored by thermal resistance (Rth) created by circuit traces (addi affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance. The peak voltages generated in the "Temperature Rise vs. Combined Ripple Currents" plot are calculated for each frequency and are not combined with voltages
- generated at any other harmonics.
  Please consult with the catalog or field applications engineer for maximum capability of the device in specific applications.

All product information and data (collectively, the "Information") are subject to change without notice.

KEMET K-SIM is designed to simulate behavior of components with respect to frequency, ambient temperature, and DC bias levels. The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation effects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

All Information given herein is believed to be accurate and reliable, but is presented without guarantee, warranty, or responsibility of any kind, expressed or implied. Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute – and we specifically disclaim – any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.

If you have any questions please contact K-SIM.